

® SDMP0340LT /LST /LCT /LAT

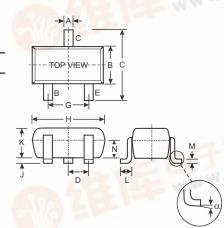
SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

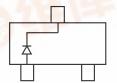
- Low Forward Voltage Drop
- Guard Ring Die Construction for Transient Protection
- Ideal for low logic level applications
- Low Capacitance
- Lead Free/RoHS Compliant (Note 3)

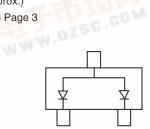
Mechanical Data

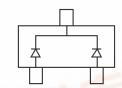
- Case: SOT-523
- Case Material: Molded Plastic. UL Flammability Classification Rating: 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Polarity: See Diagrams Below
- Marking: See Diagrams Below & Page 3
- Weight: 0.002 grams (approx.)
- Ordering Information, see Page 3

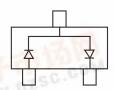


SOT-523								
Dim	Min	Max	Тур					
Α	0.15	0.30	0.22					
В	0.75	0.85	0.80					
С	1.45	1.75	1.60					
D	_	_	0.50					
G	0.90	1.10	1.00					
Н	1.50	1.70	1.60					
J	0.00	0.10	0.05					
K	0.60	0.80	0.75					
T.E.	0.10	0.30	0.22					
M	0.10	0.20	0.12					
N	0.45	0.65	0.50					
α	0°	8°	_					
All Dimensions in mm								









SDMP0340LT Marking: SM

SDMP0340LAT Marking: SQ SDMP

SDMP0340LCT Marking: SP SDMP0340LST Marking: SN

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _R WM V _R	40	V	
RMS Reverse Voltage	V _{R(RMS)}	28	V	
Forward Continuous Current (Note 1)	I _{FM}	30	mA	
Non-Repetitive Peak Forward Surge Current @8.3ms Single half sine-wave superimposed on rated load	I _{FSM}	200	mA	
Power Dissipation (Note 1)	Pd	150	mW	
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	833	°C/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-40 to +125	°C	

Electrical Characteristics @ TA = 25°C unless otherwise specified

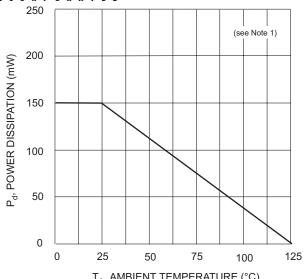
Characteristic		Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	V _{(BR)R}	40	_	_	V	I _R = 10uA
Forward Voltage Drop	VF	_	290	370	mV	I _F = 1mA
Leakage Current (Note 2)	I _R	_	_	1.0	μА	V _R = 10V
Total Capacitance	C _T	_	2	_	pF	V _R = 1V, f = 1.0 MHz

1. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

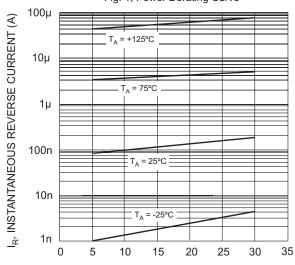
No purposefully added lead.

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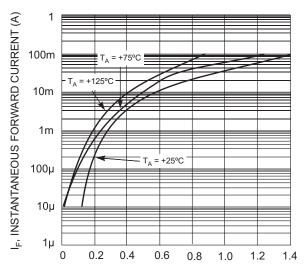
DIODES



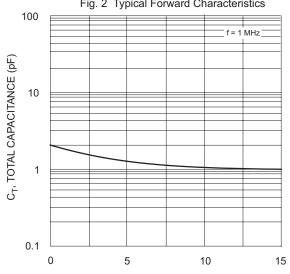




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m V_{R}}$, INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 3 Typical Reverse Characteristics



 V_{F} , INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics



 $\label{eq:VR} {\rm V_R,\,DC\,\,REVERSE\,\,VOLTAGE\,\,(V)}$ Fig. 4 Typical Capacitance vs. Reverse Voltage

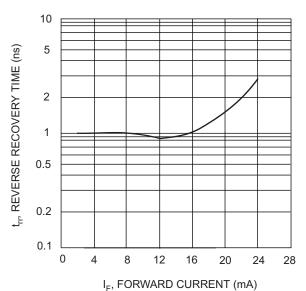


Fig. 5 Typical Reverse Recovery Time Characteristics



Ordering Information (Note 4)

Device	Packaging	Shipping
SDMP0340LT-7	SOT-523	3000/Tape & Reel
SDMP0340LST-7	SOT-523	3000/Tape & Reel
SDMP0340LCT-7	SOT-523	3000/Tape & Reel
SDMP0340LAT-7	SOT-523	3000/Tape & Reel

Notes: 4. For Packaging Details: go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XX = Product Type Marking Code (See Page 1)

YM = Date Code Marking Y = Year (ex: N = 2002) M = Month (ex: 9 = September)

Date Code Key

Year	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	М	N	Р	R	S	Т	U	V	W	Х	Υ	Z
Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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